UTC UNISONIC TECHNOLOGIES CO., LTD

M28S

NPN SILICON TRANSISTOR

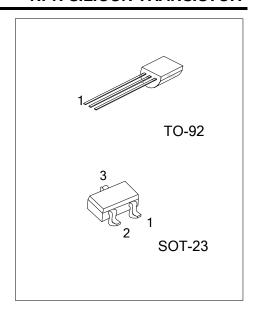
AUDIO OUTPUT DRIVER AMPLIFIER

FEATURES

- * Excellent HFE Linearity
- * High DC Current Gain
- * High Power Dissipation

APPLICATION

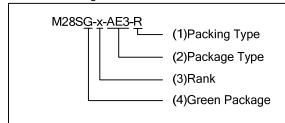
- * Audio Output Driver Amplifier
- * General Purpose Switch



ORDERING INFORMATION

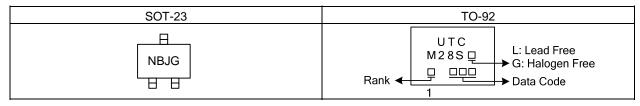
Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
-	M28SG-x-AE3-R	SOT-23	Е	С	В	Tape Reel	
M28SL-x-T92-B	M28SG-x-T92-B	TO-92	E	С	В	Tape Box	
M28SL-x-T92-K	M28SG-x-T92-K	TO-92	Е	С	В	Bulk	

Pin Assignment: B: Base Note: C: Collector E: Emitter



- (1) B: Tape Box, K: Bulk, R: Tape Reel
- (2) AB3: SOT-23, T92: TO-92
- (3) x: refer to Classification of h_{FE1}
- (4) G: Halogen Free and Lead Free, L: Lead Free

MARKING



www.unisonic.com.tw 1 of 3

■ **ABSOLUTE MAXIMUM RATING** (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	V _{CBO}	40	V
Collector-emitter Voltage	V _{CEO}	20	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current	Ic	1.25	А
Base Current	I _B	0.4	А
Power Dissipation (T _A =25°C)	P _D	850	mW
Junction Temperature	TJ	+150	°C
Storage Temperature	T _{STG}	-55 ~ + 150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Voltage	V _{CBO}	I _C =0.1mA	40			V
Collector-Emitter Voltage	V _{CEO}	I _C =1mA	20			V
Emitter-Base Voltage	V _{EBO}	I _E =0.1mA	6			V
Collector Cutoff Current	I _{CBO}	V _{CB} =35V, I _E =0			100	nA
Emitter Cutoff Current	I _{EBO}	$V_{EB}=5V$, $I_{C}=0$			100	nA
ON CHARACTERISTICS						
DC Current Gain (Note)	h _{FE1}	V _{CE} =1V, I _C =1mA	290			
	h _{FE2}	V _{CE} =1V, I _C =0.1A	300		1000	
	h _{FE3}	V _{CE} =1V, I _C =0.3A	300			
	h _{FE4}	V _{CE} =1V, I _C =0.5A	300			
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	I _C =600mA, I _B =20mA			0.55	V
SMALL-SIGNAL CHARACTERISTICS						
Current Gain Bandwidth Product	f⊤	V _{CE} =10V, I _C =50mA, f=1MHz	100			MHz
Output Capacitance	Сов	V _{CB} =10V, I _E =0, f=1MHz		9		pF

■ CLASSIFICATION OF h_{FE2}

RANK	В	С	D
RANGE	300-550	500-700	650-1000

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